LN77L

GaAlAs Infrared Light Emitting Diode

For optical control systems

■ Features

- High-power output, high-efficiency: $P_O = 18 \text{ mW (typ.)}$
- Fast response and high-speed modulation capability: $f_C = 20 \text{ MHz}$ (typ.)
- Wide directivity: $\theta = 20^{\circ}$ (typ.)
- Transparent epoxy resin package

■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter | Symbol | Rating | Unit | |
|-------------------------------|------------------|-------------|------|--|
| Power dissipation | P_{D} | 190 | mW | |
| Forward current | I_{F} | 100 | mA | |
| Pulse forward current * | I_{FP} | 1 | A | |
| Reverse voltage | V _R | 3 | V | |
| Operating ambient temperature | T _{opr} | -25 to +85 | °C | |
| Storage temperature | T _{stg} | -30 to +100 | °C | |

Note) *: f = 100 Hz, Duty cycle = 0.1%

■ Electro-Optical Characteristics $T_a = 25$ °C±3°C

| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|--------------------------|------------------------|---|-----|-----|-----|------|
| Radiant power | Po | $I_F = 50 \text{ mA}$ | 10 | 18 | | mW |
| Reverse current | I_R | $V_R = 3 V$ | | | 10 | μΑ |
| Forward voltage | V _F | $I_F = 100 \text{ mA}$ | | 1.6 | 1.9 | V |
| Peak emission wavelength | λ_{P} | $I_F = 50 \text{ mA}$ | | 860 | | nm |
| Spectral half band width | Δλ | $I_F = 50 \text{ mA}$ | | 40 | | nm |
| Half-power angle | θ | The angle when the radiant power is halved. | | 20 | | 0 |

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

2. Modulation total power output 3 dB frequency to fall from 1 MHz.

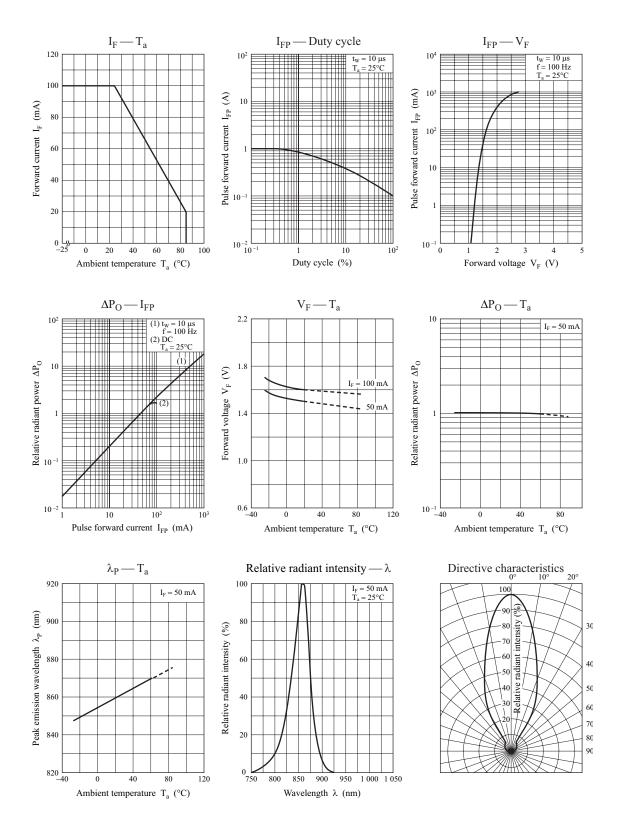
Cutoff frequency: 20 MHz

$$f_C: 10 \times log \xrightarrow{\quad P_O \text{ at } f = f_C \quad } = -3$$

- 3. LED might radiate red light under large current drive.
- 4. *: A light detection element uses a silicon diode have proofread a load with a standard device.

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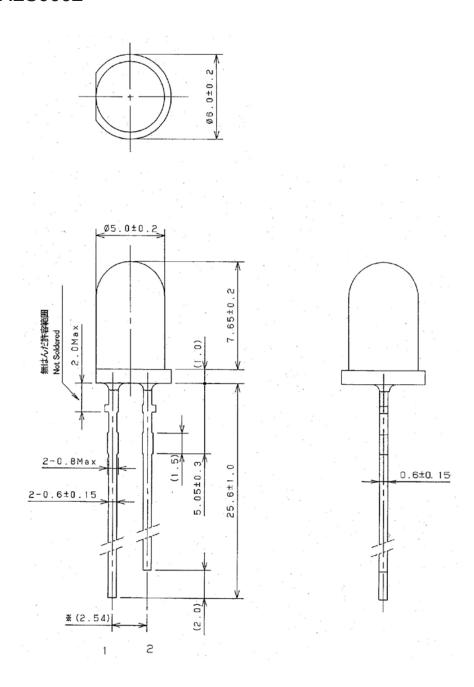


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■ Package (Unit: mm)

LEXLTN2S0002



- Pin name
 - 1: Anode
 - 2: Cathode

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